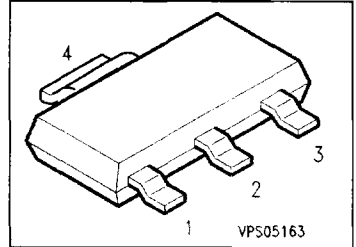


NPN Silicon AF Transistors

BCP 54
... **BCP 56**

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCP 51 ... BCP 53 (PNP)



| Type | Marking | Ordering Code (tape and reel) | Pin Configuration | | | | Package ¹⁾ |
|-----------|-----------|----------------------------------|-------------------|---|---|---|-----------------------|
| | | | 1 | 2 | 3 | 4 | |
| BCP 54 | BCP 54 | Q62702-C2117 | B | C | E | C | SOT-223 |
| BCP 54-10 | BCP 54-10 | Q62702-C2119 | | | | | |
| BCP 54-16 | BCP 54-16 | Q62702-C2120 | | | | | |
| BCP 55 | BCP 55 | Q62702-C2148 | | | | | |
| BCP 55-10 | BCP 55-10 | Q62702-C2122 | | | | | |
| BCP 55-16 | BCP 55-16 | Q62702-C2123 | | | | | |
| BCP 56 | BCP 56 | Q62702-C2149 | | | | | |
| BCP 56-10 | BCP 56-10 | Q62702-C2125 | | | | | |
| BCP 56-16 | BCP 56-16 | Q62702-C2106 | | | | | |

¹⁾ For detailed information see chapter Package Outlines.

Maximum Ratings

| Parameter | Symbol | Values | | | Unit |
|--|-----------|----------------|--------|--------|------------------|
| | | BCP 54 | BCP 55 | BCP 56 | |
| Collector-emitter voltage $R_{BE} \leq 1 \text{ k}\Omega$ | V_{CE0} | 45 | 60 | 80 | V |
| | V_{CER} | 45 | 60 | 100 | |
| Collector-base voltage | V_{CBO} | 45 | 60 | 100 | A |
| Emitter-base voltage | V_{EB0} | 5 | | | |
| Collector current | I_C | 1 | | | |
| Peak collector current | I_{CM} | 1.5 | | | mA |
| Base current | I_B | 100 | | | |
| Peak base current | I_{BM} | 200 | | | |
| Total power dissipation, $T_S = 124 \text{ }^\circ\text{C}^{1)}$ | P_{tot} | 1.5 | | | W |
| Junction temperature | T_j | 150 | | | $^\circ\text{C}$ |
| Storage temperature range | T_{stg} | - 65 ... + 150 | | | |

Thermal Resistance

| | | | |
|----------------------------------|-------------|-----------|-----|
| Junction - ambient ¹⁾ | $R_{th JA}$ | ≤ 72 | K/W |
| Junction - soldering point | $R_{th JS}$ | ≤ 17 | |

¹⁾ Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristics

at $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified.

| Parameter | Symbol | Values | | | Unit |
|-----------|--------|--------|------|------|------|
| | | min. | typ. | max. | |

DC characteristics

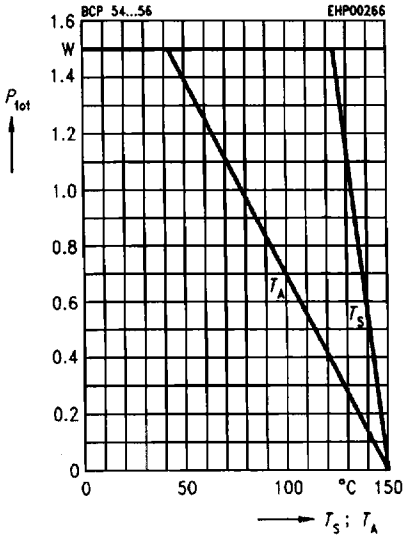
| | | | | | |
|---|---------------|-----------------------------|---------------------------|-----------------------------|---------------------|
| Collector-emitter breakdown voltage $I_C = 10\text{ mA}$, $I_B = 0$ | $V_{(BR)CEO}$ | 45 60 80 | — — — | — — — | V |
| Collector-base breakdown voltage ¹⁾ $I_C = 100\text{ }\mu\text{A}$, $I_B = 0$ | $V_{(BR)CBO}$ | 45 60 100 | — — — | — — — | |
| Emitter-base breakdown voltage $I_E = 10\text{ }\mu\text{A}$, $I_C = 0$ | $V_{(BR)EBO}$ | 5 | — | — | |
| Collector-base cutoff current $V_{CB} = 30\text{ V}$, $I_E = 0$ $V_{CB} = 30\text{ V}$, $I_E = 0$, $T_A = 150\text{ }^\circ\text{C}$ | I_{CBO} | — — | — — | 100 20 | nA μA |
| Emitter-base cutoff current $V_{EB} = 5\text{ V}$ | I_{EBO} | — | — | 10 | μA |
| DC current gain $I_C = 5\text{ mA}$, $V_{CE} = 2\text{ V}$ $I_C = 150\text{ mA}$, $V_{CE} = 2\text{ V}$ | h_{FE} | 25 40 63 100 25 | — — 100 160 — | — 250 160 250 — | — |
| Collector-emitter saturation voltage ¹⁾ $I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$ | V_{CEsat} | — | — | 0.5 | V |
| Base-emitter voltage ¹⁾ $I_C = 500\text{ mA}$, $V_{CE} = 2\text{ V}$ | V_{BE} | — | — | 1 | |

AC characteristics

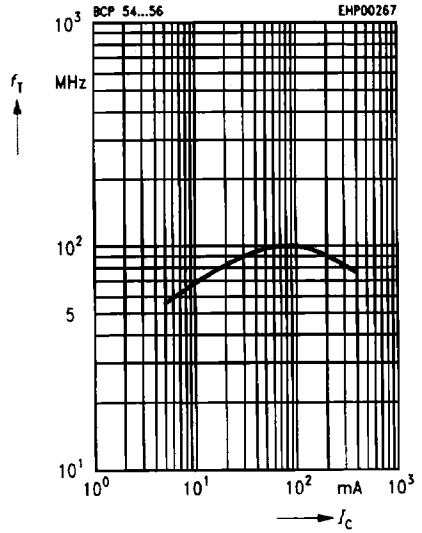
| | | | | | |
|--|-------|---|-----|---|-----|
| Transition frequency $I_C = 50\text{ mA}$, $V_{CE} = 10\text{ V}$, $f = 100\text{ MHz}$ | f_T | — | 100 | — | MHz |
|--|-------|---|-----|---|-----|

1) Pulse test conditions: $t \leq 300\text{ }\mu\text{s}$, $D = 2\%$.

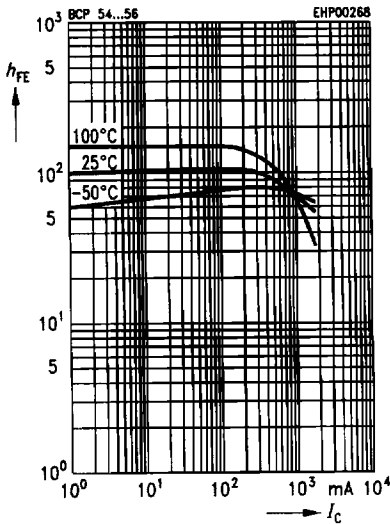
Total power dissipation $P_{tot} = f(T_A^*; T_S)$
* Package mounted on epoxy



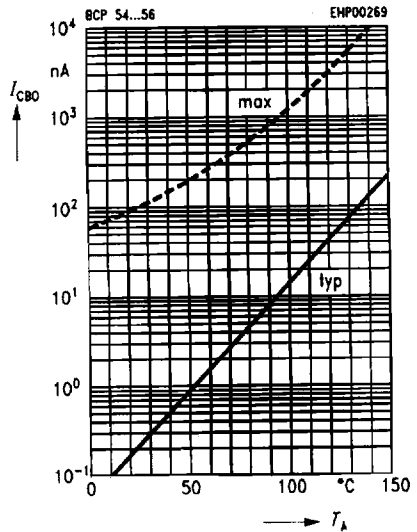
Transition frequency $f_T = f(I_C)$
 $V_{CE} = 10\text{ V}$



DC current gain $h_{FE} = f(I_C)$
 $V_{CE} = 2\text{ V}$



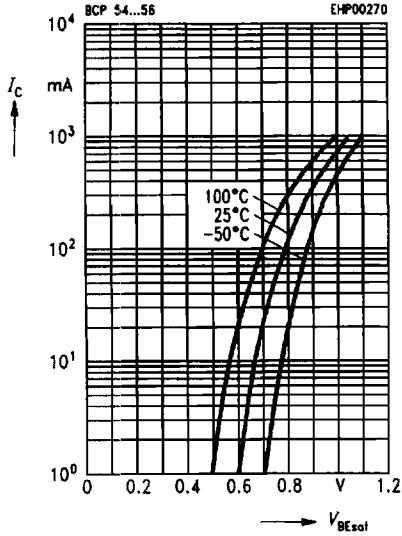
Collector cutoff current $I_{CBO} = f(T_A)$
 $V_{CB} = 30\text{ V}$



Base-emitter saturation voltage

$I_C = f(V_{BEsat})$

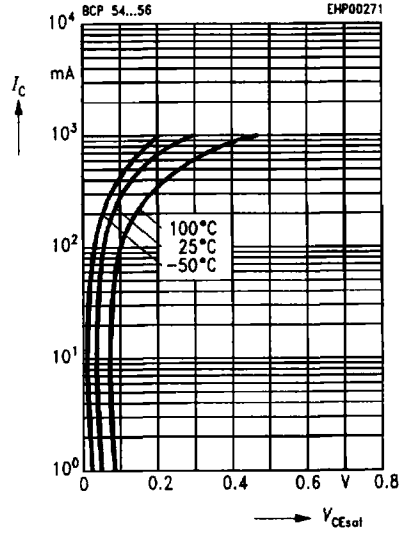
$h_{FE} = 10$



Collector-emitter saturation voltage

$I_C = f(V_{CEsat})$

$h_{FE} = 10$



Permissible pulse load $P_{tot max}/P_{tot DC} = f(t_p)$

